Diode Semiconductor Device - Page 1 of 2



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### Inclosure Material:

Metal

**Overall Length:** 

1.253 inches

# **Mounting Facility Quantity:**

1

## Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.505 inches

#### Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

10.0 regulator voltage

# Current Rating Per Characteristic:

250.00 milliamperes all primaries horsepower metric and 250.00 milliamperes repetitive peak forward current

#### Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius case

#### **Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### Thread Series Designator:

Unf

# Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

# **Specification Data:**

81349-mil-s-19500/124 government specification

# Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

Fiig:

A110a0



Mil-std (military Standard):

Mil-prf-19500 spec.